NSN 5962-01-062-0762

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View Online at https://aerobasegroup.com/nsn/5962-01-062-0762

view Offilite at https://aerobasegroup.com/hsi//0302-01-002-0702
Body Length:
Between 0.755 inches and 0.790 inches
Body Width:
Between 0.265 inches and 0.300 inches
Body Height:
Between 0.155 inches and 0.175 inches
Maximum Power Dissipation Rating:
358.4 milliwatts
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Strategic weapon systems (poseidon & trident)
Features Provided:
Hermetically sealed and monolithic and high speed and positive outputs and programmable and programmed and w/buffered output and
w/decoded output and w/disable and w/enable and w/storage and 3-state output
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Criticality Code Justification:
Feat
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
35.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Special Features:
Weapon system essential

N/a

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

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Demilitarization:

Yes - demil/mli

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